

DMTH6004SCT

Product Summary

BV _{DSS}	Rds(on) Max	ID Tc = +25°C (Note 9)
60V	3.65mΩ @ V _{GS} = 10V	100A

Description and Applications

This new generation MOSFET features low on-resistance and fast switching, making it ideal for high-efficiency power management applications.

- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

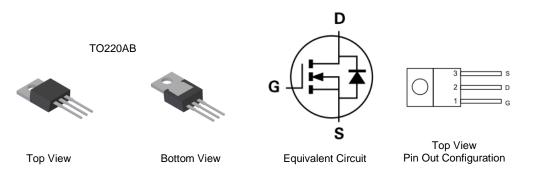
60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Low Input Capacitance
- Low Input/Output Leakage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: TO220AB
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Terminal Connections: See Diagram Below
- Weight: 1.85 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMTH6004SCT	TO220AB	50 Pieces/Tube

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



J | |=Manufacturer's Marking
H6004S = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 21 = 2021)
WW = Week Code (01 to 53)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	60	V	
Gate-Source Voltage	Vgss	±20	V	
Continuous Drain Current (Notes 6 8 0)	Tc = +25°C	1-	100	٨
Continuous Drain Current (Notes 6 & 9)	$T_{C} = +100^{\circ}C$	ID	100	A
Maximum Continuous Body Diode Forward Current (Notes 6 & 9)	Tc = +25°C	ls	100	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	ldм	180	A	
Avalanche Current, L=0.2mH	las	45	A	
Avalanche Energy, L=0.2mH	Eas	200	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.8	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	52.8	°C/W
Total Power Dissipation (Note 6)	$T_{\rm C} = +25^{\circ}{\rm C}$	PD	136	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	1.1	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	Cymber		1.7b	mux	onne		
Drain-Source Breakdown Voltage	BV _{DSS}	60	_		V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	_	—	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	lgss		—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)						·	
Gate Threshold Voltage	VGS(TH)	2	—	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	RDS(ON)		3.1	3.65	mΩ	Vgs = 10V, ID =100A	
Diode Forward Voltage	V _{SD}	_	—	1.3	V	$V_{GS} = 0V, I_{S} = 100A$	
DYNAMIC CHARACTERISTICS (Note 8)				•			
Input Capacitance	Ciss	—	4,556	—			
Output Capacitance	Coss	_	1,383	_	pF	$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	
Reverse Transfer Capacitance	Crss	_	105				
Gate Resistance	R _G	_	0.7		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Q _G	_	95.4			$V_{DD} = 30V, I_D = 90A,$	
Gate-Source Charge	QGS	_	21.6	_	nC		
Gate-Drain Charge	Q _{GD}	_	20.4	_		$V_{GS} = 10V$	
Turn-On Delay Time	tD(ON)	_	14.3	_		$V_{DD} = 30V, V_{GS} = 10V,$ $I_D = 90A, R_G = 3.5\Omega$	
Turn-On Rise Time	tR	_	99.1				
Turn-Off Delay Time	t _{D(OFF)}		40	_	ns		
Turn-Off Fall Time	tF		17.6	_	1		
Reverse Recovery Time	t _{RR}	_	50.5	_	ns		
Reverse Recovery Charge	Qrr	_	80.8		nC IF = 48A, di/dt = 100A/ μ s		

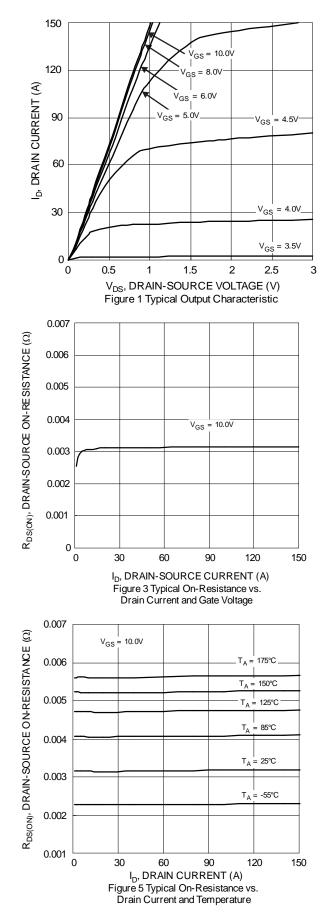
5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided. Notes:

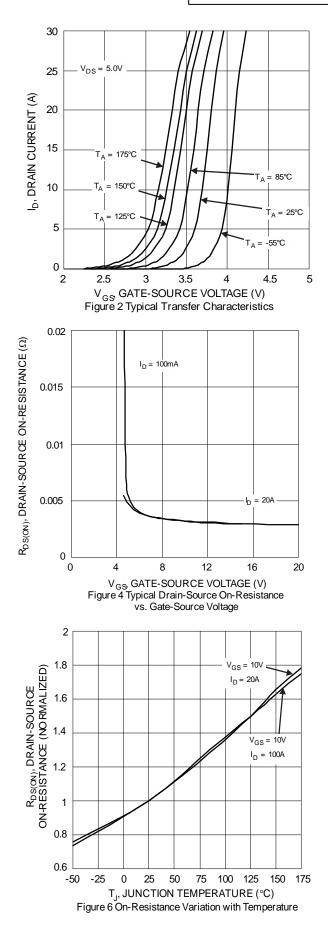
Device mounted on infinite heat sink.
 Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.
 9. Package limited.



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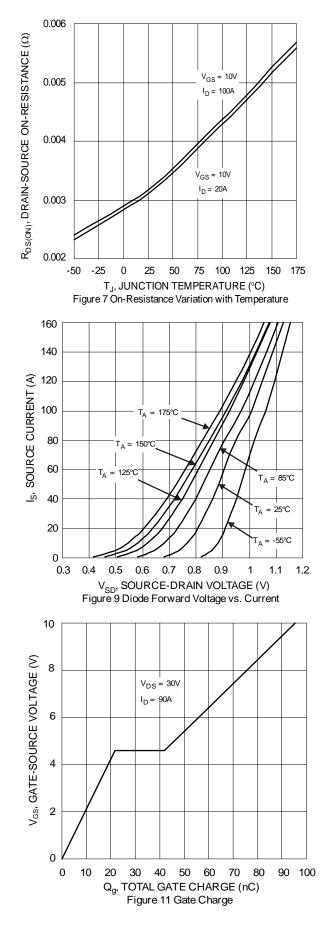


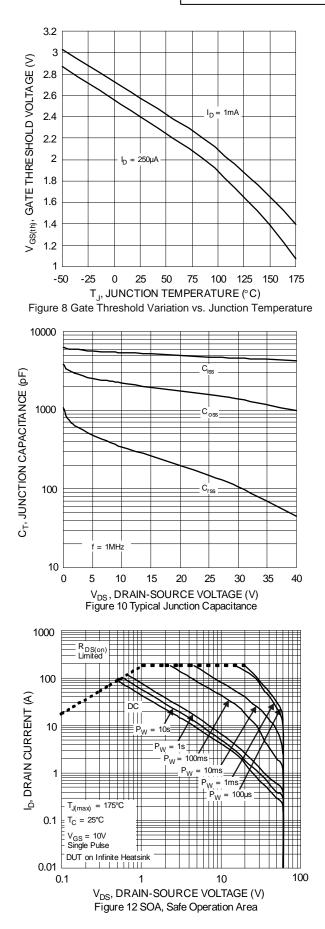


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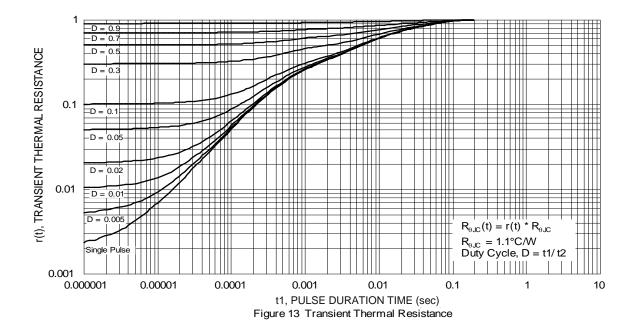






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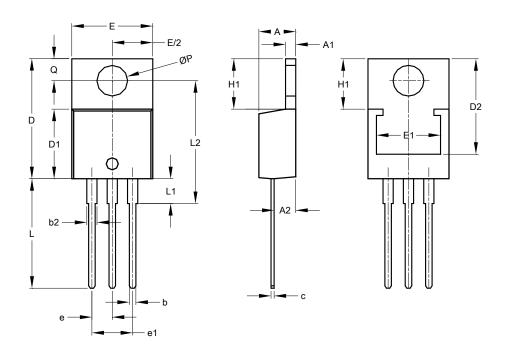






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



TO220AB

TO220AB					
Dim	Min	Max	Тур		
Α	3.56	4.82	-		
A1	0.51	1.39	-		
A2	2.04	2.92	-		
b	0.39	1.01	0.81		
b2	1.15	1.77	1.24		
С	0.356	0.61	-		
D	14.22	16.51	-		
D1	8.39	9.01	-		
D2	11.45	12.87	-		
е	-	-	2.54		
e1	-	-	5.08		
Ε	9.66	10.66	-		
E1	6.86	8.89	-		
H1	5.85	6.85	-		
L	12.70	14.73	-		
L1	-	4.42	-		
L2	15.80	17.51	16.00		
Ρ	3.54	4.08	-		
Q	2.54	3.42	-		
All Dimensions in mm					

Deekene Outline Dimension

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